Hon. Commissioner of Patents

Washington, DC 20231

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE REQUEST FOR FILING APPLICATION

Under Rule 53(a), (b) & (f) (No Filing Fee or Oath/Declaration) (Do NOT use for Provisional or PCT Applications)

Use for Design or Utility Applications **RULE 53(f) NO DECLARATION**

Atty. Dkt.

APPLICATION HD-943 Client Ref

PATENT

Date:

January 2, 2001 January 1, 2001 = Holiday December 31, 2000 = Sunday December 30, 2000 = Saturday

PM 275264

Sir:						
 This is a Request for filing 	g a new Patent Application	□ Design □ Utility) ent	itled:			
2. (Complete) Title: METHOD OF FABRICATING CAPACITORS FOR SEMICONDUCTOR DEVICES						
without a filing fee or Oath/Declaration but for which is enclosed the following:						
3. Abstract page(s).						
4. 24 Pages of Specification (only spec. and claims); 5. Specification in non-English language						
6. 20 Numbered claim(s); and						
7. Drawings: 3 sheet(s) 1 set informal; 8. of formal of size: A4 11"						
9. DOMESTIC/INTERNATIONAL priority is claimed under 35 USC 119(e)/120/365(c) based on the following provisional, nonprovisional and/or PCT international application(s):						
	Filing Date	Application No.	Fillian D. C.			
(1) Application No.	1 milg Date	(2)	Filing Date			
(3)						
(5)		(4)				
10. FOREIGN priority is claimed under 35 USC 119(a)-(d)/365(b) based on filing in Korea						
Application No.	Filing Date	Application No.	Filing Date			
(1) 33-00034	December 31, 1999	(2)				
(3)		(4)				
(5)		See 3 rd page for additi	onal priorities			
11. 1 (No.) Certified copy (copies):						
 12. This is a reissue of Patent No. 13. See top first page re prior Provisional, National, International application(s) (X box only if info is there and do not complete corresponding item 14 or 15.) 14. Amend the specification by inserting before the first line This is a Continuation-in-Part Divisional Continuation Substitute Application (MPEP 201.09) of: 						
14(a) National Appln. No. / filed filed filed sessionated the U.S., and that International Application under PCT Article 21(2) in English (M#) which which which published with the published was not with the published with						
15. Amend the specification by inserting before the first line: —This application claims the benefit of U.S. Provisional Application No. 60/, filed						
16. Extension to date: ☐ concurrently filed ☐ not needed ☐ previously filed						
17. Small Entity Status is claimed (pre-filing confirmation required)						
17(a) Attached: (No.) Small Entity Statement (s). (Since 9/8/00 Small Entity Statement not						
essential to make claim)						
17(b) See NONPUBLICATION REQUEST under Rule 213(a) attached (PAT-258)						

18. Prior applica	ition is assigned to			
by Assignment recor	ded		Reel	Frame
19. Attached:				
20. This application is n (Listing of inventor(nade by the following s) <u>not</u> a requirement,) (Double chec	k instructions for accuracy.):
(1) Inventor Kee Jeur	ng		LEE	
	First	Middle Initial		Family Name
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EL SE SE	City		te/Foreign Country	Country of Citizenship
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(include Zip Code)				
(2) Inventor Dong Jui	1		KIM	·
JP9814-34	First	Middle Initial		Family Name
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5 22 30	City		ite/Foreign Country	Country of Citizenship
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(include Zip dode)				
(3) Inventor				
(FEBRE	First	Middle Initial	-	Family Name
Residence				
AND LONG THE PARTY OF THE PARTY	City	Sta	rte/Foreign Country	Country of Citizenship
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(4) Inventor				
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residence	Joseff 1			
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(5) Inventor				
COMPANI.	First	. Middle Initial		Family Name
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Mailing Address				
(include Zip Code)				
21. NOTE: FOR ADI	et with same inform	nation regarding Pillsbury Winth Intellectual Prop	additional invento rop LLP eerty Group	rs.
1100 New York Avenue, NV Ninth Floor		Gregory P. Brumm	ett	Reg. No. 41646
Washington, DC 20005-391 Tel: (202) 861-3000	8 Sig:	MB	unmet	Fax: (202) 822-094
Atty/Sec: GPB/slb	NOTE: File in dual	licate with 2 post card	receipts (PAT-103) & a	Tel: (202) 861-368.
		Post card		